

GR QSSPA1.23

OSCONIQ® P 3030

The OSCONIQ P 3030 Colors family LED comes with well known superior robustness, high reliability, long lifetime, low thermal resistance. Compact and proven 3mm x 3mm package and established foot-print. Perfectly addressing applications that demand for high efficiency and long lifetime.



Applications

- Accent (BAR)
- Architecture
- Stage Lighting (LED & Laser)

Features:

- Package: SMD epoxy package
- Typ. Radiation: 120°
- Corrosion Robustness Class: 3B
- Lumen maintenance: Test results according to IESNA LM-80 available
- ESD: 8 kV acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 3B)
- Luminous Flux: typ. 73 lm
- Luminous Efficacy: typ. 99 lm/W

Ordering Information

Type	Luminous Flux ¹⁾ $I_F = 350 \text{ mA}$ Φ_V	Ordering Code
GR QSSPA1.23-KPKR-1-1	71.0 ... 89.2 lm	Q65112A8490
GR QSSPA1.23-KQKS-1-1	76.3 ... 97.0 lm	Q65113A2040

Maximum Ratings

Parameter	Symbol		Values
Operating Temperature	T_{op}	min.	-40 °C
		max.	125 °C
Storage Temperature	T_{stg}	min.	-40 °C
		max.	125 °C
Junction Temperature	T_j	max.	135 °C
Forward current	I_F	min.	100 mA
		max.	1000 mA
Surge Current $t \leq 10 \mu s$; $D = 0.005$; $T_j = 25 \text{ °C}$	I_{FS}	max.	1500 mA
Reverse voltage ²⁾	V_R	Not designed for reverse operation	
ESD withstand voltage acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 3B)	V_{ESD}	8 kV	

Characteristics

$I_F = 350 \text{ mA}$; $T_J = 25 \text{ °C}$

Parameter	Symbol		Values
Peak Wavelength	λ_{peak}	typ.	634 nm
Dominant Wavelength ³⁾ $I_F = 350 \text{ mA}$	λ_{dom}	min.	620 nm
		typ.	623 nm
		max.	632 nm
Spectral Bandwidth at 50% $I_{\text{rel,max}}$	$\Delta\lambda$	typ.	16 nm
Viewing angle at 50% I_V	2ϕ	typ.	130 °
Forward Voltage ⁴⁾ $I_F = 350 \text{ mA}$	V_F	min.	1.90 V
		typ.	2.18 V
		max.	2.50 V
Reverse current ²⁾	I_R		Not designed for reverse operation
Electrical thermal resistance junction/solderpoint with efficiency $\eta_e = 51 \text{ %}$	$R_{\text{thJS elec.}}$	typ.	4.2 K / W

Brightness Groups

Group	Luminous Flux ¹⁾ $I_F = 350 \text{ mA}$ min. Φ_V	Luminous Flux ¹⁾ $I_F = 350 \text{ mA}$ max. Φ_V
KP	71.0 lm	76.3 lm
KQ	76.3 lm	82.0 lm
KR	82.0 lm	89.2 lm
KS	89.2 lm	97.0 lm

Forward Voltage Groups

Group	Forward Voltage ⁴⁾ $I_F = 350 \text{ mA}$ min. V_F	Forward Voltage ⁴⁾ $I_F = 350 \text{ mA}$ max. V_F
E2	1.90 V	2.00 V
F1	2.00 V	2.10 V
F2	2.10 V	2.20 V
G1	2.20 V	2.30 V
G2	2.30 V	2.40 V
H1	2.40 V	2.50 V

Wavelength Groups

Group	Dominant Wavelength ³⁾ $I_F = 350\text{ mA}$ min. λ_{dom}	Dominant Wavelength ³⁾ $I_F = 350\text{ mA}$ max. λ_{dom}
1	620 nm	632 nm
1	620 nm	632 nm

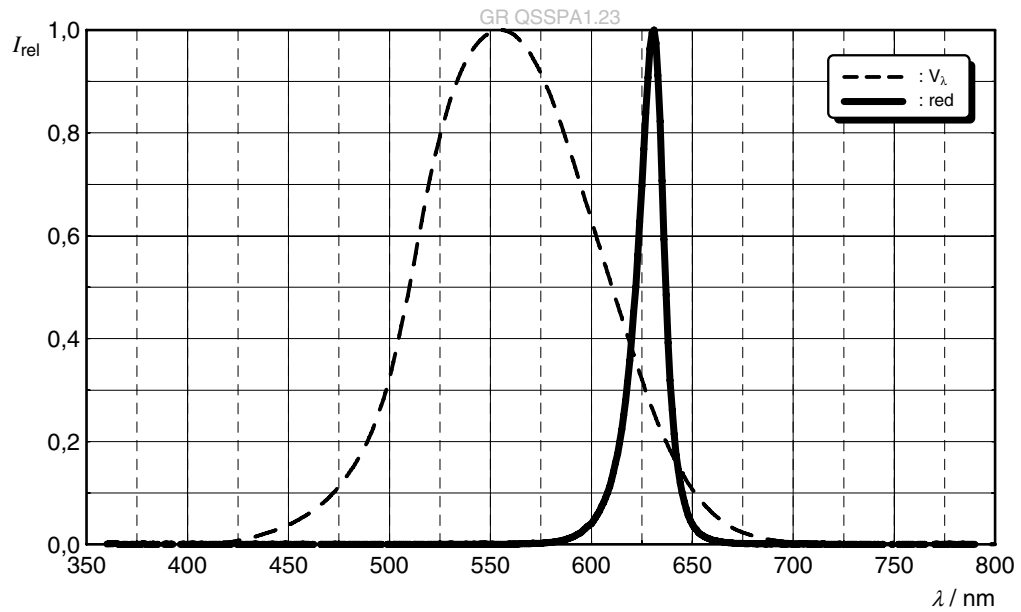
Group Name on Label

Example: KP-1-E2

Brightness	Wavelength	Forward Voltage
KP	1	E2

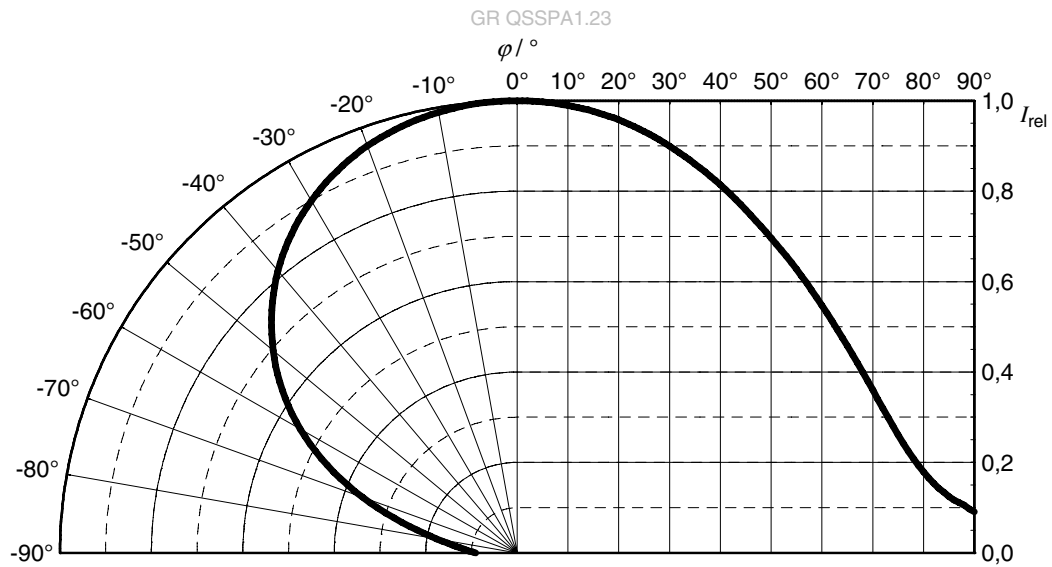
Relative Spectral Emission ⁵⁾

$I_{\text{rel}} = f(\lambda)$; $I_F = 350 \text{ mA}$; $T_J = 25^\circ\text{C}$



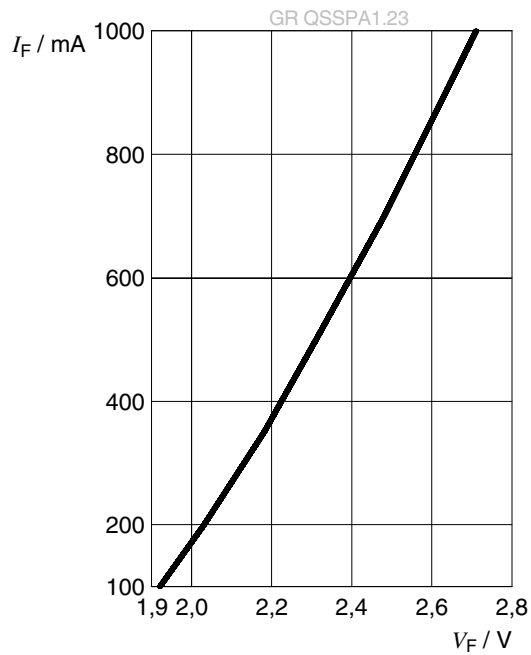
Radiation Characteristics ⁵⁾

$I_{\text{rel}} = f(\phi)$; $T_J = 25^\circ\text{C}$

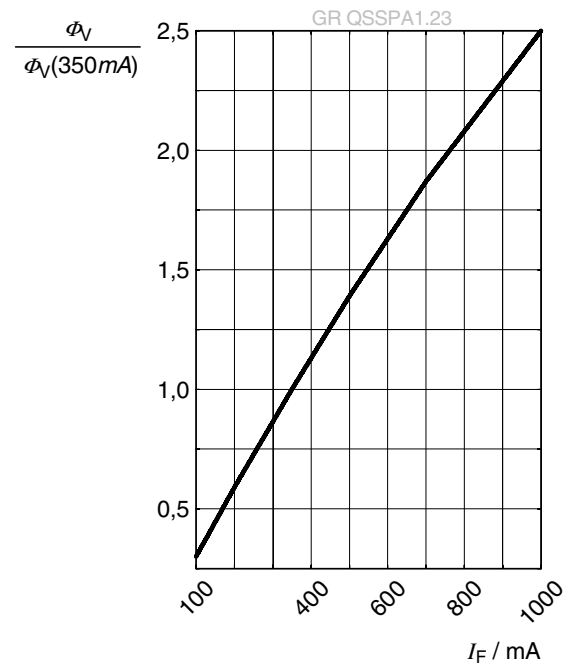


Forward current ⁵⁾

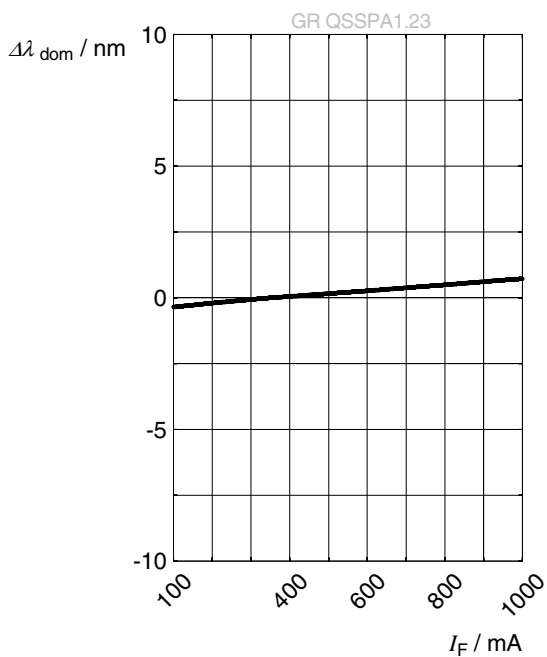
$$I_F = f(V_F); T_J = 25\text{ °C}$$

**Relative Luminous Flux** ^{5), 6)}

$$\Phi_V / \Phi_V(350\text{ mA}) = f(I_F); T_J = 25\text{ °C}$$

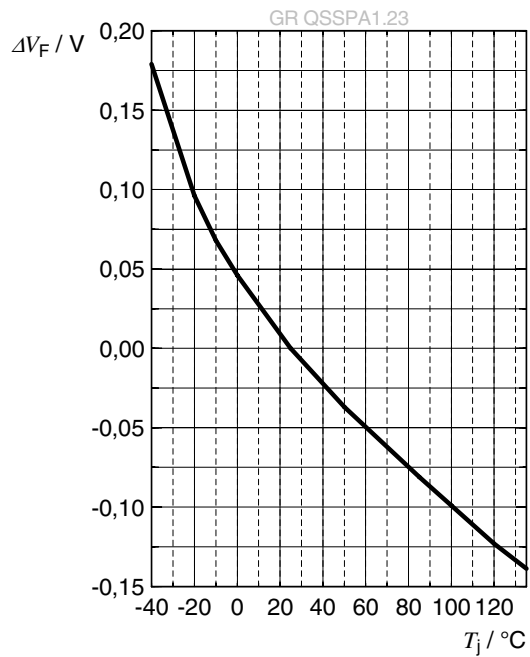
**Dominant Wavelength** ⁵⁾

$$\Delta\lambda_{\text{dom}} = f(I_F); T_J = 25\text{ °C}$$

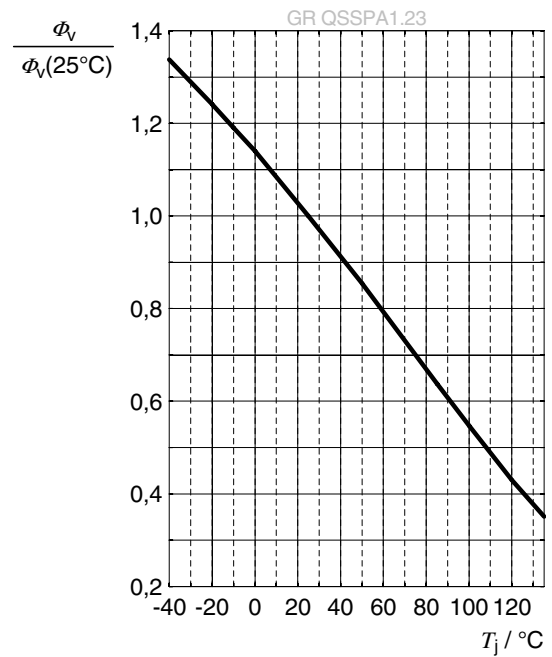


Forward Voltage ⁵⁾

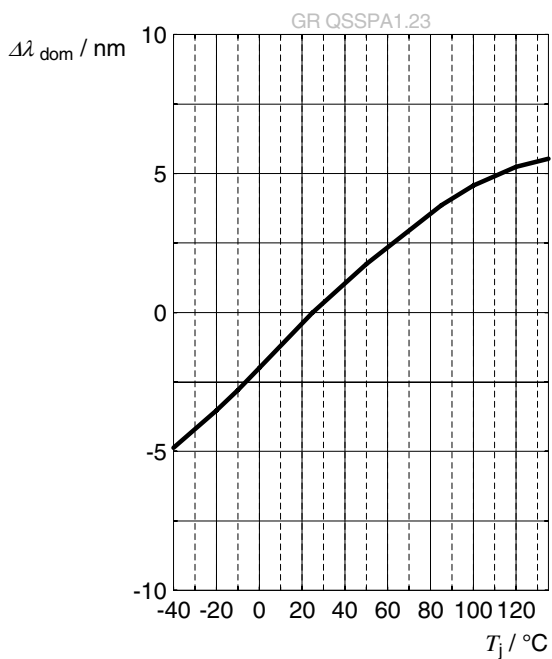
$$\Delta V_F = V_F - V_F(25^\circ\text{C}) = f(T_j); I_F = 350\text{ mA}$$

**Relative Luminous Flux** ⁵⁾

$$\Phi_V / \Phi_V(25^\circ\text{C}) = f(T_j); I_F = 350\text{ mA}$$

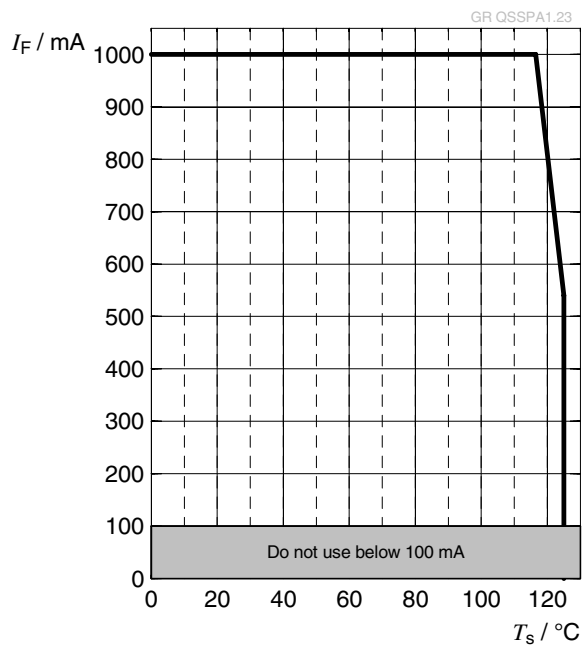
**Dominant Wavelength** ⁵⁾

$$\Delta \lambda_{\text{dom}} = \lambda_{\text{dom}} - \lambda_{\text{dom}}(25^\circ\text{C}) = f(T_j); I_F = 350\text{ mA}$$

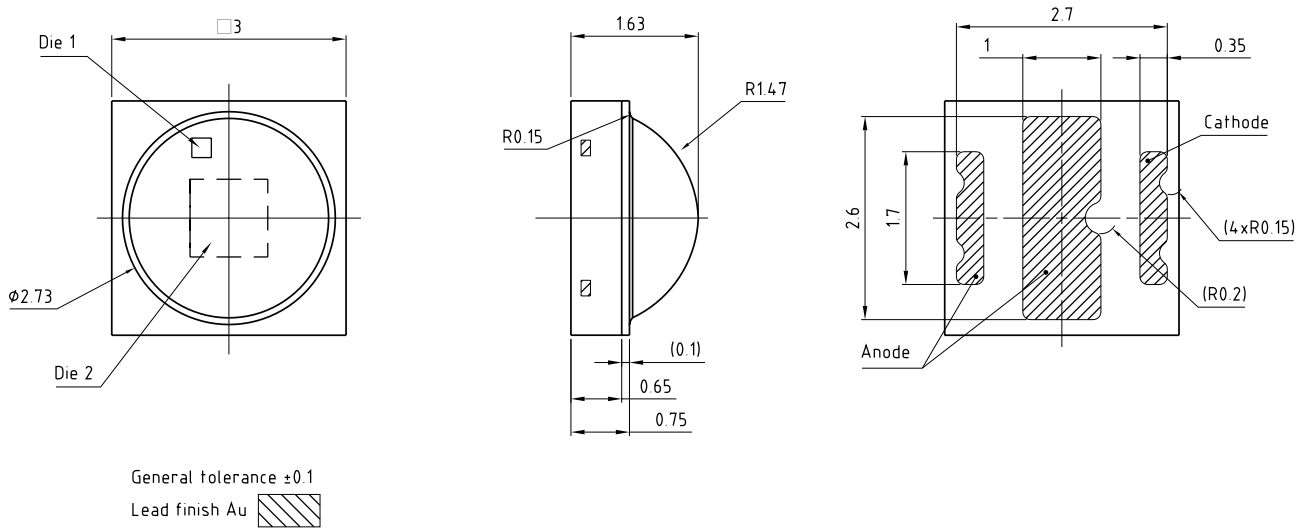


Max. Permissible Forward Current

$$I_F = f(T)$$



Dimensional Drawing ⁷⁾



C67062-A0282-A6..-03

Further Information:

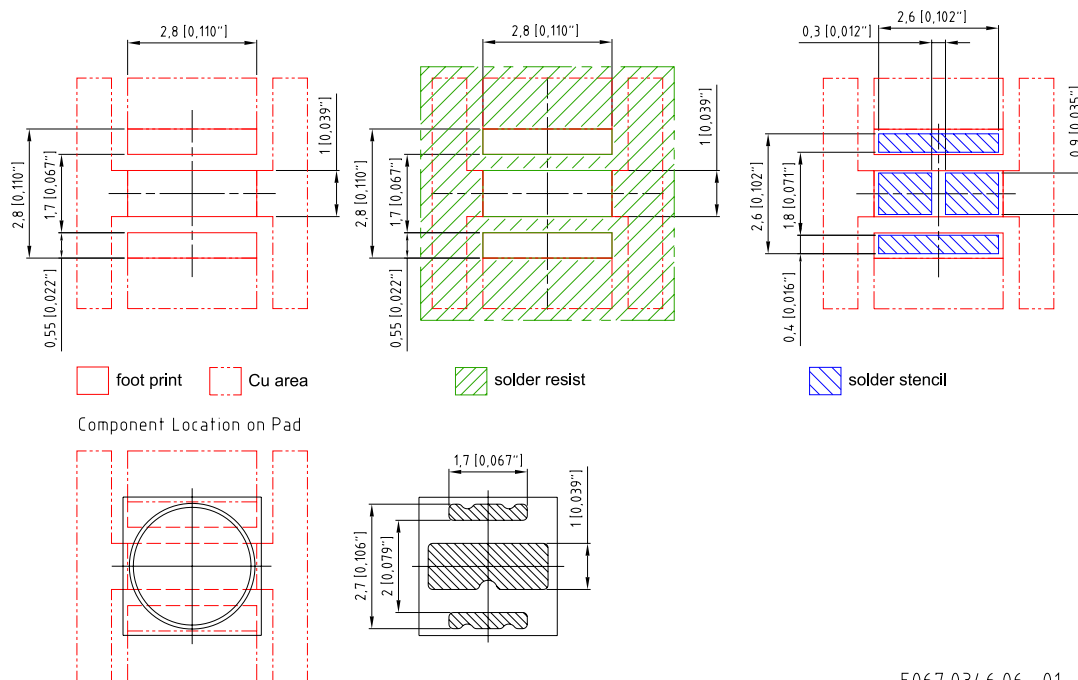
Approximate Weight: 24.0 mg

Package marking: Anode

Corrosion test: Class: 3B
Test condition: 40°C / 90 % RH / 15 ppm H₂S / 14 days (stricter than IEC 60068-2-43)

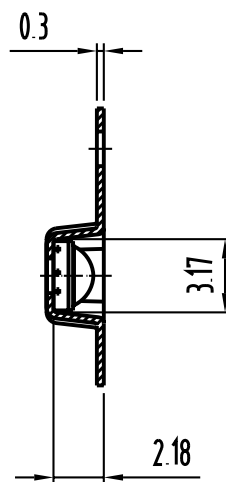
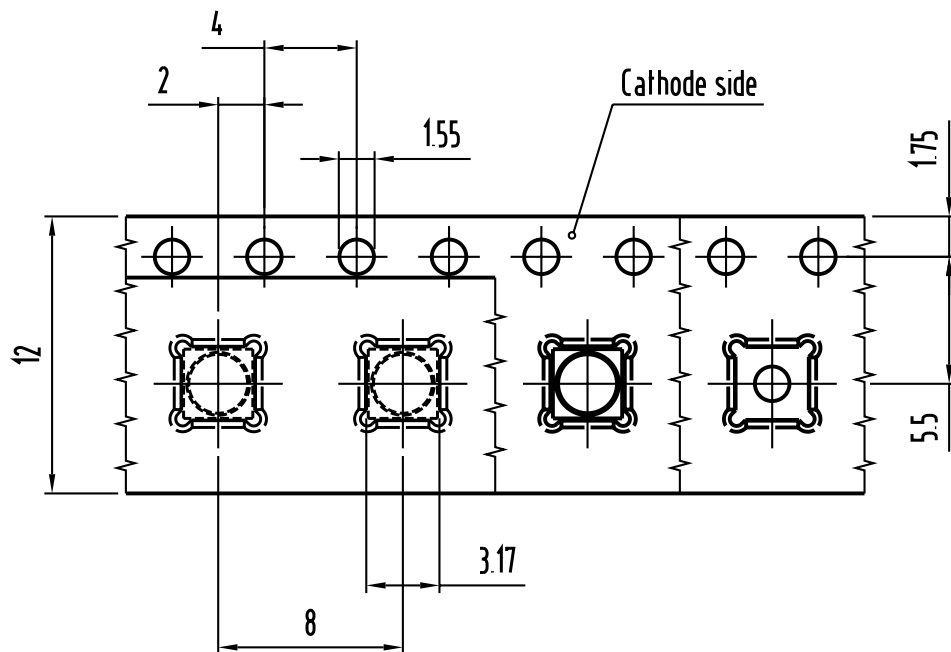
ESD advice: The device is protected by ESD device which is connected in parallel to the Chip.

Recommended Solder Pad ⁷⁾



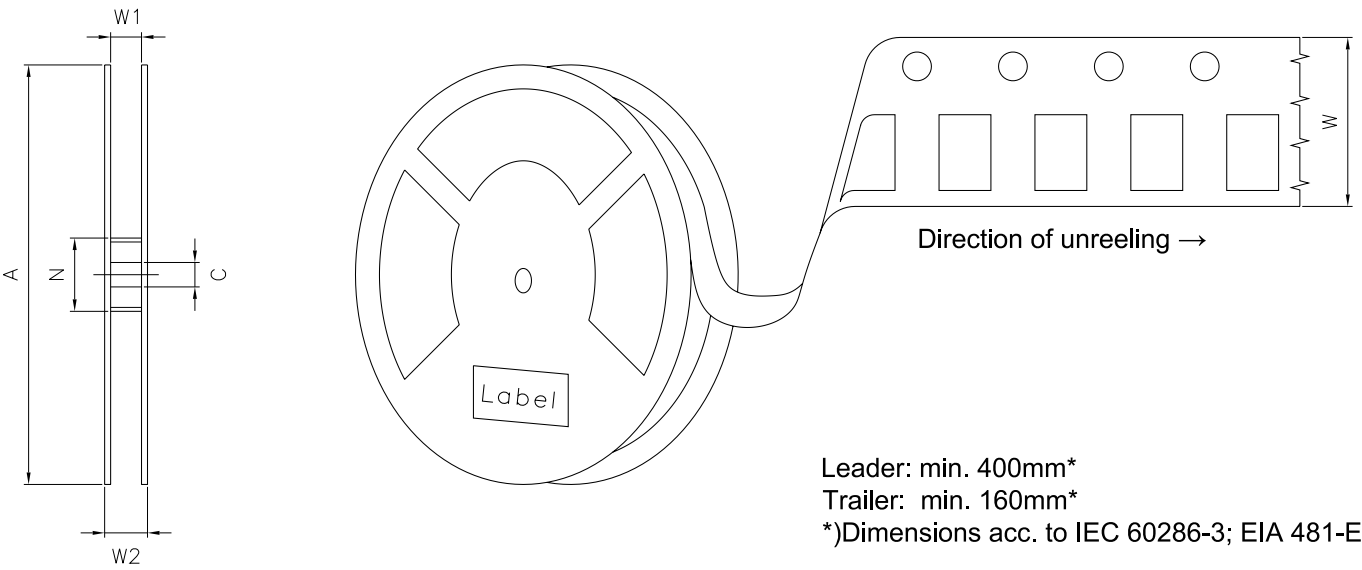
E067.0346.06 -01

For superior solder joint connectivity results we recommend soldering under standard nitrogen atmosphere. Package not suitable for ultra sonic cleaning.

Taping ⁷⁾

C67062-A0282-B10 04

Tape and Reel ⁸⁾



Reel Dimensions

A	W	N _{min}	W ₁	W _{2 max}	Pieces per PU
180 mm	12 + 0.3 / - 0.1 mm	60 mm	12.4 + 2 mm	18.4 mm	600

Barcode-Product-Label (BPL)

OSRAM Opto Semiconductors

LX XXXX BIN1: XX-XX-X-XXX-X

RoHS Compliant

(6P) BATCH NO: 1234567890

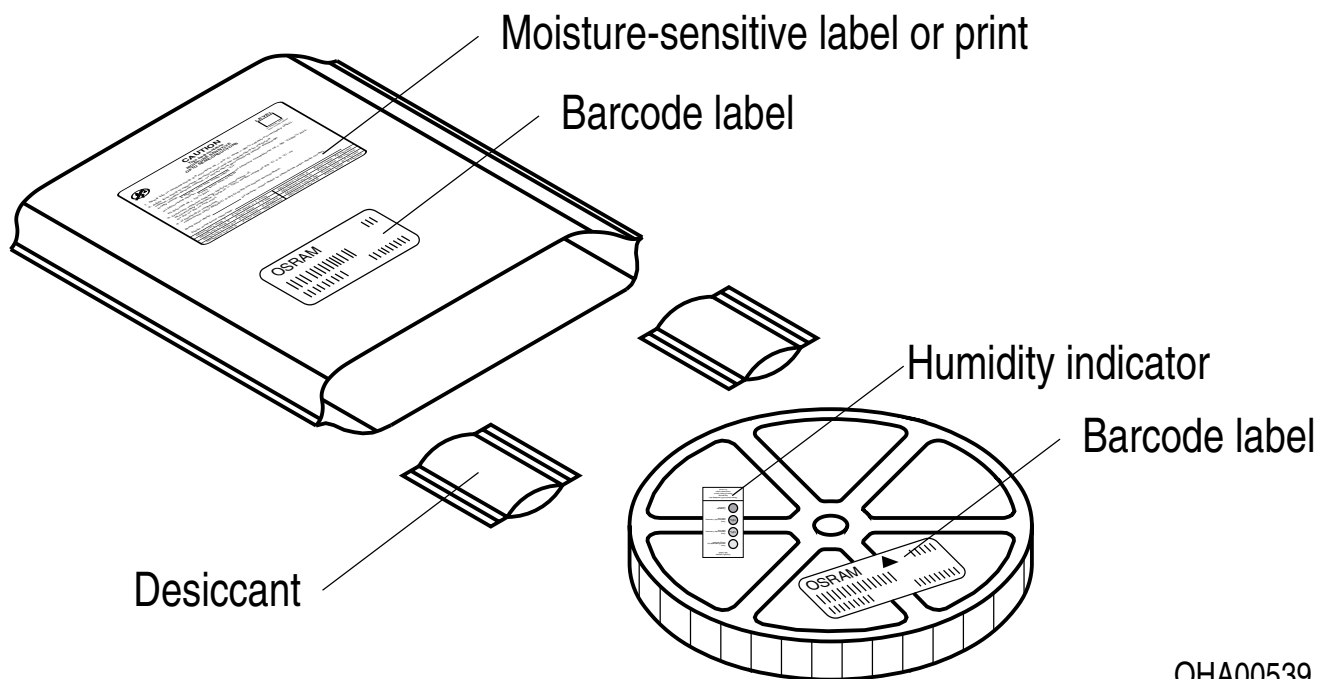
(1T) LOT NO: 1234567890 (9D) D/C: 1234

ML Temp ST
X XXX °C X

Pack: RXX
DEMY XXX
X_X123_1234.1234 X

(X) PROD NO: 123456789 (Q) QTY: 9999 (G) GROUP: XX-XX-X-X

OHA04563

Dry Packing Process and Materials ⁷⁾

Moisture-sensitive product is packed in a dry bag containing desiccant and a humidity card according JEDEC-STD-033.

Notes

The evaluation of eye safety occurs according to the standard IEC 62471:2006 (photo biological safety of lamps and lamp systems). Within the risk grouping system of this IEC standard, the device specified in this data sheet falls into the class **exempt group (exposure time 10000 s)**. Under real circumstances (for exposure time, conditions of the eye pupils, observation distance), it is assumed that no endangerment to the eye exists from these devices. As a matter of principle, however, it should be mentioned that intense light sources have a high secondary exposure potential due to their blinding effect. When looking at bright light sources (e.g. headlights), temporary reduction in visual acuity and afterimages can occur, leading to irritation, annoyance, visual impairment, and even accidents, depending on the situation.

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

This device is designed for specific/recommended applications only. Please consult OSRAM Opto Semiconductors Sales Staff in advance for detailed information on other non-recommended applications (e.g. automotive).

Change management for this component is aligned with the requirements of the lighting market.

For further application related information please visit www.osram-os.com/appnotes

Disclaimer

Attention please!

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version on the OSRAM OS website.

Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

Product and functional safety devices/applications or medical devices/applications

OSRAM OS components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

OSRAM OS products are not qualified at module and system level for such application.

In case buyer – or customer supplied by buyer – considers using OSRAM OS components in product safety devices/applications or medical devices/applications, buyer and/or customer has to inform the local sales partner of OSRAM OS immediately and OSRAM OS and buyer and /or customer will analyze and coordinate the customer-specific request between OSRAM OS and buyer and/or customer.

Glossary

- 1) **Brightness:** Brightness values are measured during a current pulse of typically 10 ms, with a tolerance of $\pm 7\%$.
- 2) **Reverse Operation:** Not designed for reverse operation. Continuous reverse operation can cause migration and damage of the device.
- 3) **Wavelength:** The wavelength is measured at a current pulse of typically 10 ms, with a tolerance of ± 0.5 nm.
- 4) **Forward Voltage:** The Forward voltage is measured during a current pulse duration of typically 1 ms with a tolerance of ± 0.05 V.
- 5) **Typical Values:** Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- 6) **Characteristic curve:** In the range where the line of the graph is broken, you must expect higher differences between single devices within one packing unit.
- 7) **Tolerance of Measure:** Unless otherwise noted in drawing, tolerances are specified with ± 0.1 and dimensions are specified in mm.
- 8) **Tape and Reel:** All dimensions and tolerances are specified acc. IEC 60286-3 and specified in mm.

Revision History

Version	Date	Change
1.0	2019-04-22	Initial Version
1.1	2020-09-09	Ordering Information

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